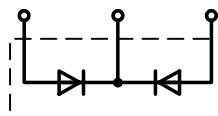


## HiPerFRED™ Epitaxial Diode with common cathode and soft recovery

$I_{FAV} = 2 \times 15 \text{ A}$   
 $V_{RRM} = 200 \text{ V}$   
 $t_{rr} = 25 \text{ ns}$

$V_{RSM}$	$V_{RRM}$	Type
V	V	
200	200	DSEC 29-02AS



TO-263



A = Anode, C = Cathode, TAB = Cathode

Symbol	Conditions	Maximum Ratings	
$I_{FRMS}$		35	A
$I_{FAVM}$	$T_c = 150^\circ\text{C}$ ; rectangular, $d = 0.5$	15	A
$I_{FSM}$	$T_{VJ} = 45^\circ\text{C}$ ; $t_p = 10 \text{ ms}$ (50 Hz), sine	140	A
$E_{AS}$	$T_{VJ} = 25^\circ\text{C}$ ; non-repetitive $I_{AS} = 2.5 \text{ A}$ ; $L = 180 \mu\text{H}$	0.8	mJ
$I_{AR}$	$V_A = 1.5 \cdot V_R$ typ.; $f = 10 \text{ kHz}$ ; repetitive	0.3	A
$T_{VJ}$		-55...+175	°C
$T_{VJM}$		175	°C
$T_{stg}$		-55...+150	°C
$P_{tot}$	$T_c = 25^\circ\text{C}$	95	W
$M_d$	mounting torque	0.45...0.55 4...5	Nm lb.in.
Weight	typical	2	g

Symbol	Conditions	Characteristic Values	
		typ.	max.
$I_R$ ①	$T_{VJ} = 25^\circ\text{C}$ ; $V_R = V_{RRM}$ $T_{VJ} = 150^\circ\text{C}$ ; $V_R = V_{RRM}$	100 0.5	$\mu\text{A}$ mA
$V_F$ ②	$I_F = 15 \text{ A}$ ; $T_{VJ} = 150^\circ\text{C}$ $T_{VJ} = 25^\circ\text{C}$	0.86 1.06	V
$R_{thJC}$		0.5	K/W
$R_{thCH}$		0.5	K/W
$t_{rr}$	$I_F = 1 \text{ A}$ ; $-di/dt = 100 \text{ A}/\mu\text{s}$ $V_R = 30 \text{ V}$ ; $T_{VJ} = 25^\circ\text{C}$	25	ns
$I_{RM}$	$V_R = 100 \text{ V}$ ; $I_F = 25 \text{ A}$ ; $-di/dt = 100 \text{ A}/\mu\text{s}$ $T_{VJ} = 100^\circ\text{C}$	3.5	4.4
			A

Pulse test: ① Pulse Width = 5 ms, Duty Cycle < 2.0 %  
 ② Pulse Width = 300  $\mu\text{s}$ , Duty Cycle < 2.0 %

Data according to IEC 60747 and per diode unless otherwise specified.

**Recommended replacement:**  
**DPG 30C200PC**

IXYS reserves the right to change limits, test conditions and dimensions.

20070731a

© 2007 IXYS All rights reserved

1 - 2

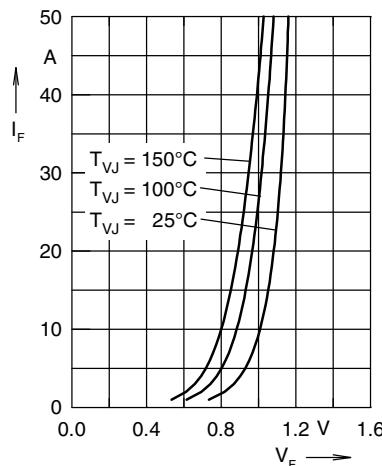
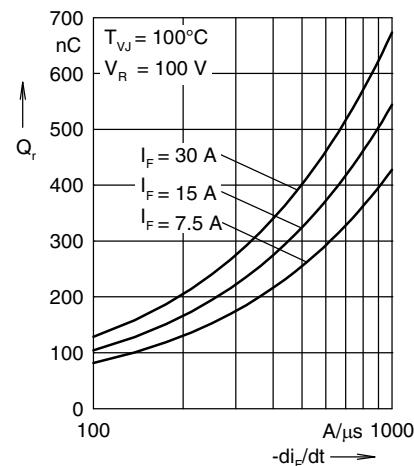
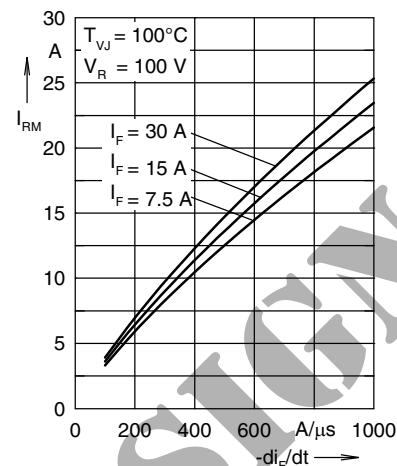
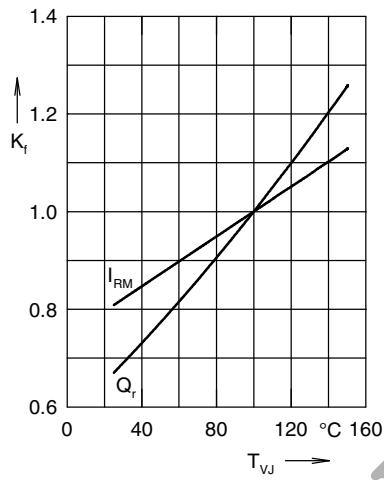
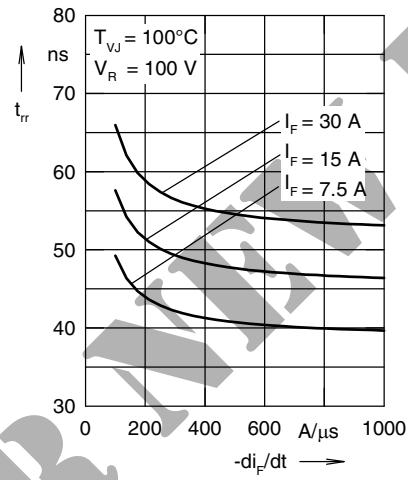
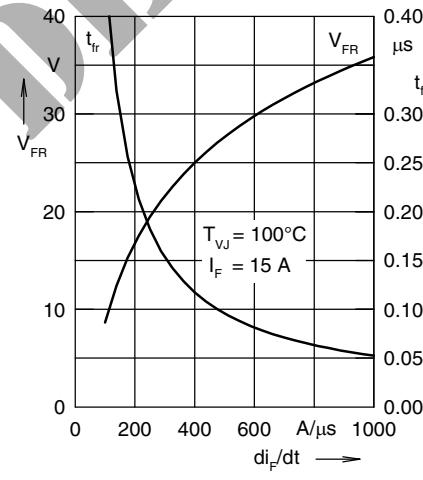
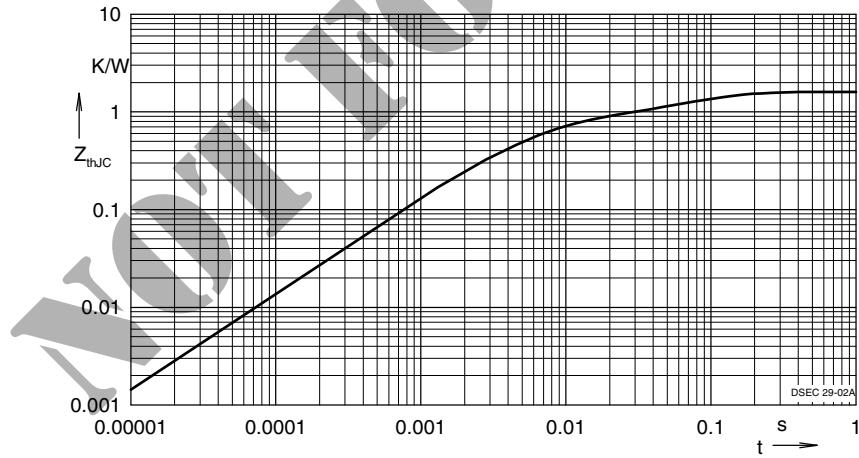
Fig. 1 Forward current  $I_F$  versus  $V_F$ Fig. 2 Typ. reverse recovery charge  $Q_r$ Fig. 3 Typ. peak reverse current  $I_{RM}$ Fig. 4 Typ. dynamic parameters  $Q_r$ ,  $I_{RM}$ Fig. 5 Typ. recovery time  $t_{rr}$  versus  $-di_F/dt$ Fig. 6 Typ. peak forward voltage  $V_{FR}$  and  $t_{tr}$ 

Fig. 7 Transient thermal resistance junction to case

Constants for  $Z_{thJC}$  calculation:

i	$R_{thi}$ (K/W)	$t_i$ (s)
1	0.851	0.0052
2	0.328	0.0003
4	0.421	0.0409